# PHYSICAL REVIEW MATERIALS 00, 004000 (2021)

# First-principles study of nickel reactivity under two-dimensional cover: Ni<sub>2</sub>C formation at rotated graphene/Ni(111) interface

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(Received 22 October 2020; accepted 24 December 2020; published xxxxxxxxx)

Recent experiments indicate that the reactivity of metal surfaces changes profoundly when they are covered with two-dimensional (2D) materials. Nickel, the widespread catalyst choice for graphene (G) growth, exhibits complex surface restructuring even after the G sheet is fully grown. In particular, due to excess carbon segregation from bulk nickel to surface upon cooling, a nickel carbide  $(Ni_2C)$  phase is detected under rotated graphene (RG) but not under epitaxial graphene (EG). Motivated by this experimental evidence, we construct different G/Ni(111) interface models accounting for the two types of G domains. Then, by applying density functional theory, we illuminate the microscopic mechanisms governing the structural changes of nickel surface induced by carbon segregation. A high concentration of subsurface carbon reduces the structural stability of Ni(111) surface and gives rise to the formation of thermodynamically advantageous Ni<sub>2</sub>C monolayer. We show the restructuring of the nickel surface under RG cover and reveal the essential role of G rotation in enabling high density of favorable C binding sites in the Ni(111) subsurface. As opposed to RG, the EG cover locks the majority of favorable C binding sites preventing the build-up of subsurface carbon density to a phase transition threshold. Therefore we confirm that the conversion of C-rich Ni surface to Ni<sub>2</sub>C takes place exclusively under RG cover, in line with the strong experimental evidence.

DOI: 10.1103/PhysRevMaterials.00.004000

# I. INTRODUCTION

Since the modern debut of graphene (G) in 2004 [1,2] 26 this first genuinely two-dimensional (2D) crystal continues 27 to exhibit scientific and technological promise across various 28 disciplines. To achieve the full potential in nanotechnology, 29 the efficient and cheap methods for producing large flakes 30 of high-quality graphene must be matured. Among presently 31 available techniques aimed towards fulfilling this goal, one 32 of the most promising is chemical vapor deposition (CVD), 33 widely used to grow graphene from carbon atoms of gaseous 34 hydrocarbons deposited on transition metal surfaces [3,4]. 35

The CVD growth of high-quality graphene largely de-36 pends on the properties of the support. Ni(111) surface is 37 a widespread choice, due to close lattice match with G and 38 the ease of dehydrogenation of precursor hydrocarbons [5–7]. 39 On the other hand, at variance with other transition metal 40 surfaces, the Ni(111) surface becomes unstable upon exposure 41 to hydrocarbons and undergoes the "clock reconstruction," 42 which leads to the formation of highly stable nickel carbide 43  $(Ni_2C)$  phase [8–10]. This structural phase transition opens 44 new possibility to grow G not directly from decomposed hy-45 drocarbons but from the precursor carbide, that is in a second 46 step converted into G [11,12]. Besides G domains aligned 47 with the nickel surface (EG), with the appropriate substrate 48

pre-treatment and the suitable choice of the CVD parameters, rotated domains (RG) can also be observed [12].

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The interplay between carbide and graphene is not limited 51 to the G growth process. Even in a presence of a complete 52 G monolayer on top of Ni(111) surface, carbide structures 53 are experimentally detected under G layer, irrespective of its 54 specific growth mechanism. Intriguingly, such carbide do-55 mains, emerged upon segregation of dissolved carbon during 56 the cooling of the sample, are found solely under RG domains 57 [12]. Even more captivating is the experimental demonstration 58 of reversible carbide formation/dissolution through the control 59 of temperature [13]. As an aftermath, this manipulation results 60 in switching of graphene electronic structure from semimetal-61 lic to metallic and vice versa. In particular, the presence of 62 carbide under the G sheet considerably affects its electronic 63 properties, as the increase of G distance from the substrate by 64  $\sim 1$  Å drastically weakens the graphene-nickel interaction and 65 restores G's semi-metallic nature. The relevance of this re-66 versible process in the design of controllable graphene/metal 67 interfaces underlines the necessity for a better understanding 68 of the reactivity of metal surface covered by 2D materials. 69 However, the microscopic mechanism that leads to the forma-70 tion of carbide under the rotated G but hinders its formation 71 under epitaxial G is still under debate. 72

In the present study, we focus on  $Ni_2C$  formed under G layer. Given that the environment under 2D cover is not easily monitored by low-energy electron diffraction (LEED) analysis or scanning tunneling microscopy (STM), we performed DFT calculation to gain additional insights on the

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ACC. CODE MX10173

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atomic structure and the reactivity of metal surfaces under 78 G cover. Concretely, we investigated the combined effects 79 of atomic carbon intercalants at G/Ni(111) interface and of 80 G rotation on the Ni<sub>2</sub>C formation. It turns out that C atoms 81 bound in Ni(111) under G trigger profound structural changes 82 in a metal layer near the surface. Ab-initio calculations shed 83 light on the origin of Ni<sub>2</sub>C formation, while the atomistic 84 picture constructed from the obtained results complements the 85 evidence from experiments. 86

We start with the description of the applied computational 87 methodology in Sec. II. The results presented in Sec. III are or-88 ganized as follows: the structural and electronic properties of 89 G epitaxially aligned and rotated at Ni<sub>2</sub>C/Ni(111) substrate, 90 EGC and RGC heterostructures, are examined in Sec. III A; 91 the microscopic mechanisms behind the formation of car-92 bide under G cover and the importance of G misalignment 93 with nickel surface for this phase transition are inspected in 94 Sec. III B. The main results are summarized in Sec. IV. 95

# **II. COMPUTATIONAL DETAILS**

First-principles calculations were carried out in the frame-97 work of spin-polarized DFT calculations using QUANTUM 98 ESPRESSO package [14,15], based on plane waves and pseu-99 dopotentials. The effects of the exchange and correlation (XC) 100 in the electronic gas were taken into account by means of 101 102 Perdew-Burke-Ernzerhof (PBE) parametrization form within 103 generalized gradient approximation (GGA) [16]. Due to an essential role of van der Waals (vdW) forces in proper descrip-104 tion of the interaction between the graphene and the nickel 105 surfaces, the dispersive corrections to the XC functional were 106 employed within the semiempirical vdW-DF2 scheme [18]. 107

The electron wave functions and the electron density were 108 expanded in plane waves basis sets with cutoff energies of 30 109 and 200 Ry, respectively. The convergence threshold for total 110 energy in all calculations was set to  $1.0 \times 10^{-6}$  Ry. In order 111 to calculate core-level shifts of C 1s states in different carbon 112 species, we constructed the ultrasoft pseudopotential with one 113 missing C 1s core electron using the ld1.x atomic code of 114 QUANTUM ESPRESSO package within the scalar-relativistic ap-115 proximation. The thorough testing is performed to assure that 116 the pseudopotential displays good transferability. According 117 to test results, provided in Ref. [17], in all calculations involv-118 ing this pseudopotential the plane wave cutoffs of the wave 119 function and electron density expansions are increased to 50 120 and 250 Ry, respectively. 121

To model the Ni(111) surface we used the lattice parameter 122 of 3.52 Å, similar to the values reported in literature obtained 123 with PBE XC functional [19]. The G/Ni(111) structures, EG 124 and RG, are modeled using a hexagonal unit cell with lateral 125 size of 10.8 Å. The G/Ni<sub>2</sub>C/Ni(111) heterostructures, EGC 126 and RGC, are modeled with monoclinic cell with lateral sizes 127 of 14.9 and 16.3 Å. The thickness of vacuum region in both 128 cases is set to at least 13 Å. During the structural relaxations, 129 the Brillouin-zone (BZ) integration has been performed with 130 4 k points using the smearing special-point technique [20,21] 131 and a smearing parameter of 0.01 Ry. All atoms but those in 132 the bottom Ni layer were allowed to relax until the forces were 133 smaller than 0.001 Ry/Bohr. Upon reaching the structural 134 equilibrium, further self-consistent calculations with fixed 135

atomic positions were performed with 16 k points in the 136 BZ. The non-self-consistent calculations with fixed poten-137 tial needed for the computation of total and atom-projected 138 density of states (DOS) were performed with 100 k points 139 in the BZ. Energy barriers in the segregation process of C 140 atom were calculated by means of the nudged elastic band 141 (NEB) method with the quasi-Newton Broyden optimization 142 scheme employed. The path was discretized into eight images 143 and the simulations were stopped when the norm of the force 144 orthogonal to the path was less than 0.1 eV/Å. We used the 145 atomic simulation environment (ASE) [22,23] for modeling 146 and displaying the structures and XCRYSDEN [24] for plotting 147 the induced charge density (ICD). 148

### **III. RESULTS AND DISCUSSION**

# A. G/Ni<sub>2</sub>C/Ni(111) heterostructures

We introduce two models of G at Ni<sub>2</sub>C/Ni(111) 151 substrate—EGC, where G is epitaxially aligned with nickel, 152 and RGC, where the angle between G zigzag direction and 153 (110) direction of Ni(111) surface is  $\sim 16^{\circ}$ . The stability of 154 two heterostructures is carefully examined by thermodynamic 155 arguments. After the models are tested by comparing the DFT-156 calculated C 1s core-level shifts with the measurements, we 157 reveal the influence of carbide on the electronic properties of 158 G cover. 159

# 1. Structural models of G at Ni<sub>2</sub>C/Ni(111) substrate

Common hexagonal crystal structure and small lattice mis-161 match allow graphene to perfectly align on top of Ni(111) 162 without moirée pattern or substantial tension. Being aligned 163 on Ni(111), the sublattices of graphene can adopt a few 164 different adsorption sites, giving rise to several EG struc-165 tures very close in energy [25,26]. The ambiguity of EG 166 structure is thoroughly examined by both theoretical and ex-167 perimental approaches with the conclusions drawn (1) that the 168 vdW forces are essential for the stability of G on Ni(111) 169 and thus must be included in DFT calculations [27,28] and 170 (2) that EG structures with different G adsorption con-171 figurations can coexist in experimental conditions due to 172 kinetic factors present during the growth [26,29]. Using DFT-173 GGA calculations with semiempirical vdW-DF2 long-range 174 dispersive corrections, Sun et al. reported that top-fcc is ener-175 getically the most favorable geometry, followed by top-bridge, 176 top-hcp, and hcp-fcc [30]. Similar results are reported by 177 Bianchini et al. [26]. Bearing in mind that our computational 178 approach is comparable to that applied in Refs. [26,30], we 179 modeled the EG structure with G adsorbed in the top-fcc 180 configuration. This choice is further corroborated by exper-181 imental findings [26,31,32]. The relevance of the particular 182 G adsorption configuration for the stability of EG will be 183 discussed in detail in Sec. III B. 184

In experimental studies on G/Ni(111) interface, the fingerprints of the post-growth carbide are found solely under rotated graphene (RGC domains) [12,13]. Moreover, combined LEED analysis and STM imaging on RGC domains showed a variety of G rotation angles [11], while further studies identified the  $17^{\circ}$  domains as the most abundant ones followed by  $13^{\circ}$  domains [13]. Most frequently, Ni<sub>2</sub>C on

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FIG. 1. RGC structure modeled with  $(6 \times \sqrt{43}) R 7.6^{\circ}$  unit cell depicted with thick black dashed lines. C atoms of G (Ni<sub>2</sub>C) are represented by small transparent red spheres (orange spheres). Ni atoms of Ni<sub>2</sub>C (Ni(111)) are represented by big light blue (dark blue) spheres. Clock reconstruction of carbide is emphasized by green and violet squares. Ni(111) lattice in the bottom is revealed on the right by removing G and Ni<sub>2</sub>C from the image. Lattice vectors **a**<sub>1</sub> and **a**<sub>2</sub> that define the  $\langle 110 \rangle$  directions of nickel lattice are depicted in the lower right corner, and adsorption sites on the nickel surface are labeled in the upper right corner. G rotation angles, measured between its zigzag directions and  $\langle 110 \rangle$  directions of Ni(111), are labeled in the middle.

Ni(111) surface is modeled with quasi-square  $\sqrt{39} R \, 16.1^{\circ} \times$ 192  $\sqrt{39} \,\overline{R} \, 16.1^{\circ}$  structure, where the denoted angles describe the 193 orientation of the unit cell vectors with respect to (110) nickel 194 surface directions and  $\bar{R}$  denotes rotation in the opposite sense 195 to R [9,33]. This structure is described already in the pioneer-196 ing work of McCaroll et al. [34], though recent studies argue 197 that the stability of  $\sqrt{39} R \ 16.1^{\circ} \times \sqrt{37} \bar{R} \ 34.7^{\circ}$  structure is 198 slightly higher [11,35]. 199

Given that G and Ni(111) surface share the same hexag-200 onal lattice with small difference in lattice constants, any 201 unit cell of Ni<sub>2</sub>C/Ni(111) interface can readily accommodate 202 the epitaxial graphene and thus can be used to model EGC 203 structure. On the other hand, when G is rotated, the problem 204 of accommodating three different lattices arises and unfortu-205 nately neither of the two aforementioned supercells is able to 206 accommodate G rotated by 17° or 13° or by any angle close to 207 it. To the best of our knowledge, nobody afforded the problem 208 of accommodation of these three lattices before. To tackle it, 209 we kept the Ni(111) lattice fixed and, by varying the struc-210 tural parameters within  $\pm 3\%$  compared to their equilibrium 211 values, simultaneously accommodated Ni<sub>2</sub>C and G lattices. 212 The details behind the construction procedure are provided in 213 Ref. [17]. 214

Our model of RGC structure is presented in Fig. 1. Among the inspected supercell candidates, we found the  $(6 \times \sqrt{43}) R 7.6^{\circ}$  to be the minimal one that is suitable to match three different lattices. Furthermore, it closely resembles the experimentally detected Ni<sub>2</sub>C structure [9] while still being computationally affordable. We used 18 C and 36 Ni atoms to build Ni<sub>2</sub>C monolayer, whilst the bulk Ni below is modeled 221 with two layers of Ni(111) containing 42 Ni atoms per layer. 222 EGC heterostructure is modeled with the same supercell, 223 with G adsorbed in the top-fcc configuration (see Fig. S2 of 224 Ref. [17]). Yet, as an aftermath of the geometric constraints 225 imposed by the shape of the (6  $\times \sqrt{43}$ ) R 7.6° supercell, the 226 number of graphene C atoms differs in two structures-the 227 G layer contains 84 C atoms in EGC and 88 C atoms in 228 RGC. In total, the EGC and RGC structures encompass 222 229 and 226 atoms, respectively. The graphene lattice constant in 230 EGC is 1.2% larger as compared to the value of pristine G 231 to satisfy the alignment condition with Ni(111). On the other 232 hand, the shape of the supercell causes small shear strain in G 233 of RGC. Consequently, the angles between zigzag directions 234 of graphene and  $\langle 110 \rangle$  directions of nickel are not equal,  $15.5^{\circ}$ 235 and  $16.1^{\circ}$ , as depicted in Fig. 1. 236

Now we focus on the structural properties and energetics 237 of EGC and RGC structures. After the structures are fully 238 relaxed, the distance between G and carbide in EGC and 239 RGC is 2.97 and 3.02 Å, respectively. For comparison, we 240 found that the height of G adsorbed on Ni(111) in the top-fcc 241 configuration is 2.10 Å, in agreement with the values reported 242 in previous studies of G adsorption on Ni(111) [26]. The total 243 energies of the two structures cannot be directly compared due 244 to different number of atoms they contain. Therefore, to quan-245 tify the influence of G orientation on the structural stability, 246 we calculated the G adsorption energy per C atom  $(E_{ads})$  in 247 EGC and RGC structures. In both cases, the  $E_{ads} = -0.10 \text{ eV}$ 248 is obtained, which is substantially smaller than -0.17 eV we 249 found for G adsorption on Ni(111) in top-fcc configuration 250 and already reported in Ref. [26]. This is in agreement with 251 the previous studies, where a weak graphene-nickel interac-252 tion is reported in cases where Ni<sub>2</sub>C is present at the nickel 253 surface [11]. Additionally, we found that the change in G 254 orientation does not affect the stability of G/Ni<sub>2</sub>C/Ni(111) 255 heterostructure, i.e. the  $E_{ads}$  is the same in EGC and RGC 256 structures. Hence, contrary to G adsorption on Ni(111) where 257 both features of chemisorption and physisorption occur [28], 258 modest  $E_{ads}$  and sizable increase in graphene-metal distance 259 suggest that G adsorption on Ni<sub>2</sub>C/Ni(111) substrate can 260 be undoubtedly characterized as a weak physisorption. In 261 the end, since EGC and RGC structures are equally stable, 262 we cannot explain why carbide formation occurs exclusively 263 under RG domains by inspecting the energetic properties of 264 these structures. Therefore the broader investigation that will 265 include the structures that precede carbide heterostructures is 266 needed. This will be afforded in Sec. III B.

# 2. C 1s core-level shifts as carbide fingerprints

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In previous experimental studies of G on Ni(111) sur-269 face, the laterally resolved x-ray photoemission electron 270 spectroscopy measurements (XPEEM) are used to identify 271 different carbon species [12,13]. Given that carbon atoms in 272 different domains have distinct chemical environments, the 273 sensitivity of the binding energy (BE) of C 1s core electrons to 274 changes in the coordination of neighboring atoms, i.e., core-275 level shifts (CLS), can be used as domain fingerprints [13]. 276 The C 1s spectra in Ref. [13] of different graphene phases on 277 Ni(111) were deconvoluted into four components, attributed 278

TABLE I. Comparison of calculated and experimental binding energies [12,13] of different carbon species on Ni(111) surface. DFT-calculated and the values obtained from the experiments are aligned with respect to the experimental BE of free graphene, 284.4 eV.

Calculated BE (eV)	Experimental BE (eV)		
Carbide C1	283.2	Carbide	283.2
Carbide C2	283.6	Dissolved C	283.8
EG (fcc, top)	284.8, 284.9	EG	284.8

to EG, weakly interacting graphene (like G in RGC), carbide,
and interstitial carbon dissolved into nickel. We report the BE
obtained from DFT calculations and suggest a possible identification of the contributions to the XPS spectra in Ref. [13],
making a comparison with the previous attribution.

The results are reported in Table I and schematically depicted in Fig. 2(b). The BE of free-standing graphene (284.4 eV) is taken as a reference.

The calculated BE of carbon atoms in G above carbide 287 is equal to the free-standing G, thus confirming once again 288 that G is decoupled from the substrate. Most often, in the 289 experimentally obtained BE of carbon structures on Ni(111), 290 the reference peak is the one ascribed to EG as it has the 291 highest intensity. However, two sublattices of EG have distinct 292 coordination, and whereas the difference in BE of C atoms 293 bound in top and fcc sites is not easy to distinguish experi-294 mentally, DFT calculations reveal small difference of around 295  $\sim$ 0.1 eV. We obtained values of 284.8 and 284.9 eV for fcc 296 and top C atoms, respectively, in excellent agreement with the 297 experimental value for EG of 284.8 eV [13]. 298



FIG. 2. (a) Two different coordinations of carbon atoms in Ni<sub>2</sub>C. C atoms represented by green (orange) spheres and labeled by 1 (2) have fivefold (sixfold) coordination of Ni atoms. In the inset the side view of a portion of Ni<sub>2</sub>C structure is presented, emphasizing different heights of C1 and C2 atoms; (b) schematic representation of core electron binding energies (in eV) for different carbon species. Experimental values are taken from Ref. [13].



FIG. 3. Charge density induced (ICD) upon G adsorption at  $Ni_2C/Ni(111)$  interface in epitaxial (a) and rotated (b) configuration. The planes used to plot ICD are denoted by dashed green lines in the upper panels and the view directions by green arrows. C atoms of G ( $Ni_2C$ ) are represented by small red (orange) spheres, and Ni atoms by larger light blue spheres. The thermographic scale on the left is in electrons/Bohr<sup>3</sup> and stands for both images.

Close examination of carbon atoms in Ni<sub>2</sub>C shows that they 299 display two different coordinations, as depicted in Fig. 2(a). 300 In particular, 1/3 of carbide C atoms, represented by green 301 spheres (C1), are surrounded by four Ni atoms laying in the 302 same plane and have one Ni atom underneath, which makes 303 their coordination fivefold. For C1, we obtained the BE of 304 283.2 eV which perfectly matches the experimentally mea-305 sured BE ascribed to carbide structure (Table I). On the other 306 hand, 2/3 of carbide C atoms, represented by orange spheres 307 (C2), are adsorbed in bridge site above the two Ni atoms of 308 the first Ni(111) layer. Thus, their coordination is sixfold and 309 we obtained BE of 283.6 eV for C2 atoms. 310

The BE of carbon atoms dissolved in the first few subsur-311 face Ni(111) layers reported in Ref. [13] is 283.8 eV, very 312 close to the value we obtained for C2 atoms. Therefore we 313 suggest that the peak attributed in Ref. [13] to dissolved C 314 could be alternatively attributed to (or could contain a contri-315 bution from) the C2 atoms of carbide. Its very low intensity 316 can be explained by structural arguments, as C2 atoms are 317 0.4 Å deeper than C1 atoms [see inset in Fig. 2(a). Thus 318 they are at the very end of the reach of photoelectrons whose 319 effective attenuation length is reported to be  $\sim$ 4.4 Å [13]. 320 Apart from this detail that would require further investiga-321 tion, the overall agreement between the calculated and the 322 experimentally obtained BE values is a firm support for our 323 computational models of carbide structures. 324

#### 3. Other electronic properties of carbide structures

To reveal how the change in G orientation affects its electronic structure, we calculated the charge density induced  $^{326}$  (ICD) upon the G adsorption on Ni<sub>2</sub>C/Ni(111) substrate  $^{328}$  (Fig. 3).  $^{329}$ 

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From ICD plots small electronic charge transfer of similar magnitude from G to Ni<sub>2</sub>C has been found both in EGC and RGC. Löwdin population analysis of valence charge projected on atomic orbitals showed that C atoms of graphene lose 0.05 electrons irrespective of G orientation, while the mean



FIG. 4. Atomic projected density of states of s and p orbitals (pDOS) averaged over the C atoms of G in EGC and RGC structures, and total DOS of free-standing G. Fermi levels of the corresponding structures are aligned to zero of the energy scale.

value of electronic charge gained on Ni atoms of carbide is 335 0.06 electrons. Changes in charge of C atoms in carbide are 336 even smaller and do not exceed 0.02 electrons. Thus, by sup-337 porting the ICD plots with the results from Löwdin analysis, 338 we conclude that the small portion of electrons transferred 339 from graphene to Ni<sub>2</sub>C is redistributed mainly between the 340 Ni atoms of Ni<sub>2</sub>C. The charge of Ni atoms in Ni(111) is 341 unaffected by graphene adsorption. 342

As reported in Ref. [13], microprobe angle-resolved photo-343 electron spectroscopy ( $\mu$ -ARPES) measurements performed 344 on RGC domains clearly show the Dirac cone (DC), a feature 345 distinctive of free-standing G, lying very close to  $E_{\rm F}$ . To 346 expose the influence of G orientation on the position of DC, 347 we compared the atomic projected density of states (pDOS) 348 of G in EGC and RGC to total DOS of free-standing G, as 349 depicted in Fig. 4. 350

Despite the fact that DC cannot be easily located in Fig. 4 351 because pDOS calculations require very dense k grid to 352 smooth the numerical oscillations, from the plot can be ra-353 tionalized that the DC in both EGC and RGC heterostructures 354 is located within a  $\sim 0.1$  eV interval around  $E_F$ . The higher 355 DOS near  $E_{\rm F}$  of EGC and RGC as compared to free-standing 356 G includes the contribution from p states of carbide C atoms 357 in the projections. The appearance of DC at the energies close 358 to  $E_F$  is a clear fingerprint of free-standing G which proves 359 that its semimetallic nature is completely restored upon the 360 formation of carbide on Ni(111) surface, while the striking 361 similarity between the pDOS of G in EGC and RGC indicates 362 that the change in G orientation does not affect its electronic 363 properties. 364

#### B. Towards carbide formation at G/Ni(111) interfaces

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The reconstruction of nickel surface upon exposure to hydrocarbons is not distinctive only of fcc(111) surface. For instance, an increase in carbon concentration up to 0.5 monolayer (ML) on Ni(100) triggers the local displacement of Ni atoms which ends with the formation of an alternate arrangement of rhombi and squares [36]. Another example is the formation of carbide structure on Ni(110) surface, which is 372 accompanied by a long-range mass transport of Ni atoms [37]. 373 Experimental findings from this study suggest that carbon is 374 most probably not embedded in the first Ni layer but must be 375 subsurface. Both Ni(100) and Ni(110) examples imply that 376 upon the increase in concentration of surface and/or subsur-377 face C atoms the nickel surfaces become unstable, while it is 378 evident that the type of the reconstruction and the critical C 379 concentration needed to trigger the structural phase transition 380 are highly dependent on the experimental conditions. 381

To examine the reconstruction of Ni(111) surface, we compared the relevant thermodynamic quantities of two structural phases: (1) the initial Ni(111) structure with added surface and/or subsurface C atoms and (2) the carbidic phase formed on Ni(111) surface. We assume that carbide C atoms are supplied from the subsurface *oh* sites and calculate the carbide formation energy per Ni<sub>2</sub>C unit as 382

$$\Delta E_f = \frac{1}{N} (E(\operatorname{Ni}_2 C/\operatorname{Ni}(111)) - E(\operatorname{Ni}(111))) - N \times E(C) - 2N \times E(\operatorname{Ni}^{fcc})), \quad (1)$$

where  $E(Ni_2C/Ni(111))$  is the total energy of  $Ni_2C/Ni(111)$ 389 structure and N is the number of  $Ni_2C$  units in the supercell. 390 Other terms are: E(Ni(111)) is the total energy of Ni(111) 391 slab, E(C) = E(C/Ni(111)) - E(Ni(111)) is the total en-392 ergy difference between the Ni(111) with one C atom in the 393 subsurface oh site and the total energy of pristine Ni(111), 394 and the last term  $E(Ni^{fcc})$  is the total energy of a Ni atom 395 in the bulk fcc crystal. The estimated formation energy is 396  $\Delta E_f = -0.3$  eV. Together with the experimental evidence of 397 surface carbide structures [9], this suggests that the preference 398 for Ni<sub>2</sub>C formation grows as the C concentration increases. 399 However, the critical concentration of C atoms needed to 400 trigger the structural phase transition and the role of G cover is 401 still under debate. In this section we discuss the microscopic 402 mechanisms leading to carbide formation under G and the 403 necessity of G rotation for such process to happen. 404

# 1. Influence of rotation on G binding to Ni(111)

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Now we discuss how the G rotation affects its stability on 406 the Ni(111). Bearing in mind that carbon concentration plays 407 a crucial role in carbide formation on Ni(111), we will explore 408 the structural phase transition taking place under the EG and 409 RG. Considering that a full carbide layer is not present in the 410 structures which will be examined here, only two different 411 lattices are to be matched: Ni(111) and G rotated with re-412 spect to  $\langle 110 \rangle$  directions of nickel. Therefore, by applying 413 the construction algorithm explained in Sec. III A 1 and in 414 Ref. [17], we searched for the smallest possible cell able to 415 accommodate G rotated by 17° or 13° chosen as the two most 416 abundant angles among experimentally obtained RG domains. 417 We found that the  $(\sqrt{19} \times \sqrt{19}) R 23.4^{\circ}$  cell is the most 418 suitable candidate, able to accommodate G rotated by  $13.2^{\circ}$ 419 (Fig. 5). By exploiting the fact that Ni(111) surface share the 420 lattice with G, the rotation angle can be easily found if one 421 notices that this supercell corresponds to linear combination 422 of unit vectors  $3\mathbf{a}_1 + 2\mathbf{a}_2$  and applies Eq. (2) from Ref. [38]. 423 Modeled with  $(\sqrt{19} \times \sqrt{19}) R 23.4^{\circ}$  cell, both EG and RG 424 structures contain 95 atoms-three layers of Ni(111) with 19 425



FIG. 5. Structural models of a) EG and b) RG made with ( $\sqrt{19} \times \sqrt{19}$ ) *R* 23.4° unit cell. In (a), the surface and the subsurface sites of EG are represented by green and gold spheres, respectively. In (b), the structural details of the unit cell are denoted, in particular: length of the unit cell vectors and the angles between them and (110) crystallographic directions of nickel. Ni(111) surface lattice vectors are depicted by yellow arrows. The G rotation angle, measured between the (110) nickel direction and the zigzag direction of G is 13.2°. Green sphere in the middle depicts the most stable surface site for binding C atom directly under RG.

Ni atoms per layer and 38 C atoms of graphene. Furthermore,
the STM images we obtained from DFT calculations (see
Fig. S3 in Ref. [17]) are in excellent agreement with the
experimental ones presented in Fig. S6 of Ref. [13] for G
domains rotated by 13°.

Now we discuss how the G orientation affects its binding 431 on Ni(111) and determines its stability. To clearly distinguish 432 between the carbon atoms of G from those possibly at the 433 G/Ni(111) interface, we label the former as  $C_G$  and the latter 434 will be simply called C atoms. Direct comparison of total 435 energy of EG and RG structures yields the difference of 436 1.48 eV (0.04 eV/C<sub>G</sub> atom on average) in favor of EG. This 437 is a clear indication that G prefers to align with Ni(111). 438 We argue that the difference in total energy of EG and RG 439 stems from different number of strong C<sub>G</sub>-Ni bonds in two 440 structures, i.e., from different number of  $C_G$  atoms adsorbed 441 in (or very near) top sites. As stated in Sec. III A 1 the most 442 favorable EG adsorption geometry is top-fcc, where half of 443 the  $C_G$  atoms are on *top* of Ni atoms while the other half are 444 above the fcc sites. Given that  $C_G$  atoms residing in different 445 sites do not contribute equally to the G adsorption energy, 446 one can estimate their individual contributions by applying 447 the following procedure. We assumed that  $C_G$  atoms of EG 448

can reside in one of those three sites: top, fcc, and hcp. Then, 449 using  $1 \times 1$  unit cell with two C<sub>G</sub> atoms, we inspected three 450 EG configurations, namely top-fcc, top-hcp, and fcc-hcp. EG 451 configurations with  $C_G$  atoms residing in bridge sites are not 452 considered. For each configuration we calculated the adsorp-453 tion energy of the two  $C_G$  atoms. With a simple algebra, from 454 three EG configurations we extracted adsorption energies of 455  $C_G$  atoms at three different sites. Finally, we found that a 456 single  $C_G$  atom adsorbed in top, fcc, and hcp site contributes 457 to the adsorption energy of G sheet by -0.23, -0.11, and 458 -0.08 eV, respectively. The much larger contribution of top 459 site as compared to the other two is a firm clue that the 460 number of  $C_G$  atoms siting in *top* sites determines the stability 461 of G/Ni(111) structure – the higher the number of occupied 462 top sites, the greater the stability. We consider the  $C_G$  atom 463 of RG bounds in the top site if the distance between its 464 projection on the Ni surface and the closest Ni atom is less 465 than 0.5 Å. In our models of EG and RG structures depicted 466 in Fig. 5, there are 19 and 8  $C_G$  atoms sitting in top sites, 467 respectively. If we assume that  $C_G$  atoms not bound in *top* 468 sites are bound somewhere between *fcc* and *hcp* sites, as the 469 rule of thumb the difference between the two contributions 470 is  $(19 - 8) \times (0.23 - (0.11 + 0.08)/2) = 1.49$  eV, which is 471 roughly the difference in total energies of EG and RG struc-472 tures. 473

# 2. Binding of an individual C atom at Ni(111) surface: Effects of G cover

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We continue with the exploration of the effect that G cover 476 has on the nickel reactivity by comparing the binding of an 477 individual C atom on clean Ni(111) to those under EG and 478 RG. We considered three surface sites—top, fcc, and hcp-479 and three subsurface sites between the second and the first 480 Ni layer, namely: octahedral (oh), tetrahedral-up (thu), and 481 tetrahedral-down (*thd*). Binding sites are depicted in Fig. 5(a). 482 The corresponding binding energies  $(E_{\text{bind}})$  are defined as 483

$$E_{\text{bind}} = E(C) + E(\operatorname{Sup}) - E(C/\operatorname{Sup}), \qquad (2)$$

where E(C) is the total energy of the isolated C atom in a box, E(Sup) is the total energy of the support, i.e.,  $Sup = \{Ni(111), EG, RG\}$ , and E(C/Sup) is the total energy of C atom bound to the support. The  $E_{bind}$  values are presented in Table II.

C atom displays very strong binding on pristine Ni(111) 488 surface, with Ebind of 6.96 and 6.90 eV corresponding to 489 hollow hcp and fcc sites. The highest  $E_{bind}$  corresponding 490 to hollow sites are also reported in the previous studies of 491 carbon adsorption on the Ni(111) surface [39,40]. At vari-492 ance with  $C_G$  atoms of graphene, which prefer to bind to 493 top site, an individual C atom is unstable in top site and 494 relaxes to *hcp* site, indicating that the formation of a single 495 C-Ni bond is unfavorable. This suggests that the character 496 of C-Ni bond crucially depends on the hybridization of C 497 2p orbitals. The overlap between the G  $\pi$  orbitals, formed 498 upon  $sp^2$ -hybridization, and the Ni  $3d_{r^2}$  orbitals is essential 499 for G stability on Ni(111) [28]. On the other hand, a single C 500 atom, which lacks  $sp^2$ -hybridized orbitals, prefers to bind in 501 sites with high Ni coordination. Similarly, a top-fcc G flake 502 terminates with  $C_G$  atoms in hollow rather than top sites [41]. 503

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TABLE II. Binding energy  $E_{\text{bind}}$  (in eV) of an individual C atom in different surface and subsurface substrate sites of pristine Ni(111), and at EG and RG interfaces. The dashes (-) indicate unstable binding sites and the stars (\*) denote the values averaged over fcc- and hcplike sites under RG.

Site			
System	top	fcc	hcp
Ni(111)	_	6.90	6.96
EG	2.69	5.30	-
RG	-	5.99*	6.12*
	oh	thu	thd
Ni(111)	7.46	6.41	_
EG	7.18	5.98	5.52
RG	7.39	-	_

Once the Ni(111) is covered with G, the  $E_{\text{bind}}$  at the 504 surface sites substantially decrease, indicating the strongly 505 repulsive character of the interaction between the C atom 506 and G cover (see Table II). This interaction combines ge-507 ometric and electronic effects. The former gives rise to a 508 marked difference in the fcc and hcp binding sites under 509 G. To simplify the discussion we refer to binding of C atom 510 on the free-standing G—the  $E_{\text{bind}}$  at the hollow site (above 511 the center of the G hexagon) is as much as 2.04 eV lower 512 than the value corresponding to a C atom bound on top of a 513  $C_G$  atom. Qualitatively, the same binding picture is found in 514 G/Ni(111) interface. In EG interface, C atom that is bound 515 in hcp site directly below G hollow site is unstable and re-516 laxes to subsurface thd site [see Fig. 5(a)]. Contrarily, it is 517 stable in fcc site under C<sub>G</sub> atom although the  $E_{bind}$  is greatly 518 reduces compared to the value obtained for the same site 519 of clean Ni(111). Considering C binding in RG [Fig. 5(b)], 520 every Ni(111) surface site is unique due to distinctions in local 521 coordination of  $C_G$  atoms. Nonetheless, the geometric effect 522 of G cover is present, as the only stable surface sites are Ni-523 threefold hollow sites with  $C_G$  atom directly above them, such 524 as the *hcp*-like site denoted by green sphere in the middle of 525 Fig. 5(b). 526

Difference in C binding under EG from that under RG can 527 be explained by electronic effect with a simple understanding 528 offered by the *d*-band model of Hammer and Nørskov [42]. 529 Here we will focus on two particular Ni-threefold hollow sites 530 with a  $C_G$  atom directly above it—(any) fcc site under EG 531 and hcp-like site under RG denoted in Fig. 5(b). DOS plot 532 in Fig. 6 shows changes induced by G cover in the electronic 533 properties of the surface Ni atoms surrounding these sites. 534

The Ni 3d states centers are at -1.84 and -1.65 eV with 535 respect to Fermi levels of EG and RG structures. According 536 to the *d*-band model, the pronounced electronic structure ef-537 fect, quantified by a decrease in the *d*-band center values of 538 surface Ni atoms, is expected to slightly reduce the reactivity 539 of the metal surface when EG is compared to RG. Entirely in 540 agreement with DFT calculations, the model predicts weaker 541 C binding under EG (inset of Fig. 6). Finally, the combined 542 geometric and electronic effects of G cover drastically reduce 543  $E_{\text{bind}}$  of C atom as compared to pristine Ni(111) surface. 544



FIG. 6. Density of states (DOS) projected on 3*d* orbitals averaged over the Ni atoms nearest to C in the most stable surface sites under EG and RG cover. Arrows indicate the position of *d*-band center. The correlation between  $E_{\text{bind}}$  of C atom and the position of *d*-band center is plotted in the inset. The Fermi energy is set to zero.

# 3. Binding of an individual C atom in Ni(111) subsurface

Now we describe C binding in subsurface, in particular between the second and the first Ni layer. Although the G cover does not affect the subsurface C atoms as much as the ones on the surface, the importance of its alignment with nickel surface is observable in any process that is accompanied by displacements of surface Ni atoms.

Among three considered subsurface sites [see Fig. 5(a)], 552 we found the *oh* site by far the most favorable one. The high 553 stability of C atom bound in oh site originates from high 554 Ni coordination, as it is surrounded by six Ni atoms at the 555 distance of 1.86 Å. The  $E_{\text{bind}}$  for *oh* site in pristine Ni(111) 556 and under EG and RG is 7.46, 7.18, and 7.39 eV, respectively. 557 These values are much larger than the  $E_{\text{bind}}$  for any surface site 558 in the corresponding structures. The preference of subsurface 559 over surface sites are in agreement with the previous studies of 560 C adsorption on Ni(111) [40,43]. Here, we stress out that the 561 binding of C atom to oh site under EG is slightly weaker than 562 in pristine Ni(111) or under RG. The reason behind this are  $C_G$ 563 atoms of EG which hold tight the Ni atoms underneath and 564 hinder their displacement from the ideal fcc(111) positions. 565 Therefore the unreleased stress of surface Ni atoms under 566 EG cover reduces the binding of C atom in oh site. To put 567 it differently, EG causes the locking of the nickel surface. 568

To investigate the possibility of a C atom in *oh* site to 569 segregate to surface *fcc* site under EG and RG, we used the 570 NEB method to calculate the barriers (Fig. 7). The fcc site 571 is chosen as the only surface site stable both under EG and 572 RG. The calculated barriers of 2.23 and 1.51 eV in EG and 573 RG structures indicate that the segregation of a single C atom 574 is very unlikely to occur as long as Ni(111) surface is intact, 575 i.e., as long as Ni atoms remain in fcc(111) positions. On the 576 other hand, much smaller barriers of 0.36 and 0.17 eV for 577

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FIG. 7. Barriers for segregation of C atom from *oh* to fcc site under EG (blue squares) and RG (red circles) as calculated via NEB method. The initial and the final image of segregation under RG is depicted in the inset.

dissolution, i.e., for the diffusion from *fcc* to *oh* site, suggest that the stability of C atom on the surface at room temperature is arguable.

High barrier for surface segregation and low barrier for 581 dissolution together with high  $E_{\text{bind}}$  for shallowest oh sites 582 indicate that an increase in subsurface C concentration is to be 583 expected. Moreover, the higher barrier for segregation under 584 EG can be explained by the fact that the migration of C atom 585 to subsurface must be followed by local displacements of 586 surface Ni atoms which are held tight by EG above. This is 587 another consequence of locking of the nickel surface, which 588 is of key importance for hindering the carbide formation under 589 EG. 590

To rationalize the preference of C atoms to occupy bulk 591 regions in nickel, we calculated  $E_{\text{bind}}$  for *oh* sites between the 592 third and the second Ni layer. These calculations were done 593 with five Ni layers. In pristine Ni(111) and under RG, the  $E_{\text{bind}}$ 594 of C atom in bulk oh site is, respectively, 0.32 and 0.23 eV 595 lower as compared to the subsurface oh site. In previous stud-596 ies the lower binding energy of bulk interstitials, i.e., C atoms 597 bound in voids deep inside the metal, as compared to the 598 subsurface interstitials, is ascribed to an enhancement of the 599 elastic response energy [43]. Indeed, the high Ni-coordination 600 of subsurface sites equal to that of bulk sites leads to higher 601  $E_{\text{bind}}$  than the values corresponding to the surface sites, while 602 the ability of surface Ni atoms to displace and optimize the 603 length of C-Ni bonds gives the preference to binding of C 604 atoms in the subsurface. 605

Contrary to C binding in Ni(111) and RG structures, in EG 606 we found no difference in  $E_{\text{bind}}$  corresponding to *oh* sites of 607 different depth. Similar finding is reported in Ref. [44], where 608 the difference between the  $E_{\text{bind}}$  of subsurface and subsubsur-609 face C atom is only 0.1 eV for G-Ni distance of 2.0 Å. We 610 explain the equal  $E_{\text{bind}}$  corresponding to *oh* sites of different 611 depth as another manifestation of locking of the nickel sur-612 face, as surface Ni atoms are unable to move and optimize the 613 length of C-Ni bonds. Furthermore, this may be an indication 614 that C atoms dissolved in bulk Ni in samples where both EG 615 and RG domains are present upon segregation would prefer 616



FIG. 8. The mean absolute displacement  $\langle d \rangle$  of surface Ni atoms (top) and the incremental binding energy  $\Delta E_{\text{bind}}$  for the addition of subsurface C atoms to *oh* sites (bottom) in EG (blue) and RG (red) at various concentrations  $\Theta$ . Top view of RG structures with  $\Theta = 0.11, 0.26$ , and 0.42 ML are presented in the middle, with the points in graph corresponding to these structures emphasized by semitransparent red circles.

to increase their concentration in the subsurface regions under RG. However, to fully examine the C segregation in EG and RG domains, more advanced models of G/Ni(111) interfaces that would include the depth gradient of carbon concentration must be considered, which is out of the scope of this work. 622

# 4. Increasing the concentration of subsurface C atoms under EG and RG

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Experimental studies of carbide formation under RG sug-625 gest that C atoms, needed for this process, are supplied from 626 inner layers. Upon cooling, the C atoms dissolved into bulk 627 nickel segregate to surface [13]. This is a common trend 628 when C is an impurity in materials, since its bulk solubility 629 reduces with temperature [45]. The structural phase transi-630 tion from C enriched Ni layers to carbide occurs when the 631 critical concentration  $\Theta_{crit}$  of subsurface carbon is reached. 632 Here, we inspect how an increase in  $\Theta$  affects the structural 633 properties of Ni(111) layers near the surface, covered by EG 634 and RG. 635

Following the preference of C atom to bind in subsurface 636 oh site, we simulated the increase in the concentration of 637 subsurface carbon in EG and RG structures by sequentially 638 adding C atoms one-by-one to oh sites. Due to geometrical 639 constraints imposed by the shape of the  $(\sqrt{19} \times \sqrt{19}) R 23.4^{\circ}$ 640 unit cell, the structures with homogeneous coverage of sub-641 surface C atoms cannot be realized for every considered 642 concentration. Therefore first we put C atoms into mutually 643 distant oh sites to suppress the C-C interaction and then we 644 add the C atoms in the oh sites in between. To quantify the 645 deformation of nickel surface upon carbon addition, we calcu-646 lated the mean absolute displacement  $\langle d \rangle$  of Ni atoms from the 647 first layer from their initial positions in EG and RG, Fig. 8(a). 648 Finally, as a measure of the energy gain upon carbon addition, 649 we calculated the incremental binding energy  $\Delta E_{\text{bind}}$  for every additional subsurface C atom put in G/Ni(111) interface, as shown in Fig. 8(b).

At low concentrations not exceeding  $\Theta \sim 0.3$  ML in both 653 structures, the mean nickel displacement is increasing lin-654 early with an increase in concentration, without substantial 655 dislocation of Ni atoms from their initial positions. Also, 656  $\Delta E_{\text{bind}}$  changes only slightly around the value obtained for the 657 binding energy of an individual C atom. This indicates that 658 at low  $\Theta$  both in EG and RG the Ni(111) structure sustains 659 carbon addition. 660

However, at  $\Theta \sim 0.35$  ML, there is an opposite variation 661 in  $\Delta E_{\text{bind}}$  in two structures. In EG, the abrupt decrease in 662 663  $\Delta E_{\text{bind}}$  suggests that further increase in carbon concentration becomes unfavorable. This is in a sharp contrast with the 664 behavior in RG where the increase in  $\Delta E_{\text{bind}}$  indicates extra 665 energy gain for every additional subsurface C atom, i.e., the 666 growing tendency of RG structure to increase the concentra-667 tion of subsurface carbon. From the steep increase of mean 668 displacement of surface Ni atoms under RG cover [Fig. 8(a)], 669 we conclude that the critical concentration for triggering the 670 phase transition is close to 0.35 ML. However, to precisely 671 obtain the  $\Theta_{crit,RG}$  one must use much larger supercell that 672 allows finer  $\Theta$  variations. 673

The physical mechanism behind the different trends ob-674 served for  $\Delta E_{\text{bind}}$  in two structures originates from the locking 675 of the nickel surface caused by EG cover. Under RG, already 676 at  $\Theta \sim 0.35$  ML the surface Ni atoms are noticeably dislo-677 cated from their fcc(111) positions. This manifestation of the 678 ongoing phase transition is substantially different from the 679 behavior observed under EG cover, where nickel surface is 680 held tight under G due to a strong overlap of G  $\pi$  and Ni 681  $3d_{7^2}$  orbitals. Therefore it is much harder to displace surface 682 Ni atoms in EG than in RG. Consequently, when nickel is 683 covered with EG, the fcc(111) structure is still preserved at 684  $\Theta \sim 0.4$  ML. 685

Within the inspected  $\Theta$  interval in EG we did not observe 686 structural manifestations of the ongoing phase transition. 687 Moreover, the vast decrease of  $\Delta E_{\text{bind}}$  under EG cover ra-688 tionalized from Fig. 8(b) shows that at  $\Theta > 0.35$  ML further 689 addition of C atoms is very unfavorable. Together with the 690 conclusions drawn from the inspection of C binding to oh 691 sites of different depth (Sec. III B 3), this can explain the 692 inability of C atoms to increase their concentration under 693 EG up to the phase transition threshold. Finally, we ar-694 gue that  $\Theta_{crit,RG}$  should depend on G rotation angle, as 695 the G misalignment determines the number of short C<sub>G</sub>-Ni 606 bonds and thus the extent to which the surface is locked, 607 which is maximal under EG and gradually reduces as G is 698 rotated. 699

### **IV. CONCLUSIONS**

Applying DFT calculations we studied the role of G cover 701 on the reactivity of Ni(111) surface and microscopic mecha-702 nisms for the Ni<sub>2</sub>C formation observed in recent experiments. 703 Structural models of G/Ni(111) and G/Ni<sub>2</sub>C/Ni(111) het-704 erostructures were constructed and validated by comparison 705 with available experimental data. In particular, the complex 706 structural model for RGC shows a fair agreement between 707 calculated C 1s core-level shift of different carbon species in 708 G/Ni<sub>2</sub>C/Ni(111) heterostructure and the corresponding mea-709 surements. We found a substantial weakening of additional 710 C atoms binding at Ni(111) beneath the G layer which is 711 rationalized by inspecting local surface Ni 3d electronic states 712 and applying the *d*-band model. Furthermore, we proved that 713 G cover even induces the destabilization of C adsorption sites 714 at Ni(111) surface. For the restructuring of nickel surface and 715 the formation of Ni<sub>2</sub>C, the near-surface carbon density must 716 increase up to a phase transition threshold. The epitaxially 717 grown G completely locks the nickel surface, making progres-718 sively more difficult the C enrichment of Ni outermost layers, 719 hindering the surface reconstruction and thus preventing the 720 nickel carbide formation. When G cover is rotated with re-721 spect to Ni(111) surface, the C binding picture changes, the 722 density of subsurface carbon can increase, reaching the criti-723 cal concentration (estimated around 0.35 ML) which enables 724 the structural transition of the C-enriched Ni(111) layer to a 725 Ni<sub>2</sub>C monolayer. Our study explains why carbide is experi-726 mentally detected only under rotated G domains, suggesting 727 the possibility of employing 2D covers to tune the metal 728 surface reactivity and improve performance concerning target 729 catalytic reactions. 730

### ACKNOWLEDGMENTS

We acknowledge financial support from the Italian Min-732 istry of Foreign Affairs and International Cooperation (Ex-733 ecutive Programme with Serbia 2019-2021 - "Progetti di 734 Grande Rilevanza") and the University of Trieste (program 735 "Finanziamento di Ateneo per progetti di ricerca scientifica 736 - FRA 2018"). This work has been also supported by the 737 project "FERMAT - Fast ElectRon dynamics in novel hy-738 brid organic-2D MATerials" funded by the MIUR Progetti di 739 Ricerca di Rilevante Interesse Nazionale (PRIN) Bando 2017 740 - grant 2017KFY7XF. We acknowledge PRACE for awarding 741 us access to Beskow supercomputer hosted by the PDC Cen-742 tre for High Performance Computing, KTH Royal Institute 743 of Technology, Sweden. Other computational resources have 744 been obtained from CINECA through the ISCRA initiative 745 and the agreement with the University of Trieste. We thank 746 Cristina Africh and Cinzia Cepek for fruitful discussions. 747<mark>FQ</mark>

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